





#### 20V NPN LOW SATURATION TRANSISTOR

### **Features and Benefits**

- BV<sub>CEO</sub> > 20V
- I<sub>C</sub> = 4.5A Continuous Collector Current
- Low Saturation Voltage (150mV max @ 1A)
- R<sub>SAT</sub> = 47 mΩ for a low equivalent On-Resistance
- h<sub>FE</sub> specified up to 6A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R<sub>θJA</sub> efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

#### **Applications**

- MOSFET Gate Driving
- DC-DC Converters
- · Charging circuits
- Power switches
- Motor Control

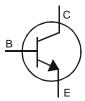
#### DFN2020B-3



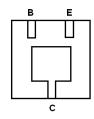




**Bottom View** 



Device Symbol



Bottom View Pin-Out

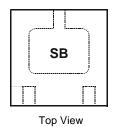
## Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN618MATA	SB	7	8	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

# Marking Information



SB = Product Type Marking code



## Maximum Ratings @TA = 25°C unless otherwise specified

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	40		
Collector-Emitter Voltage		V <sub>CEO</sub>	20	V	
Emitter-Base Voltage		V <sub>EBO</sub>	7		
Peak Pulse Current		I <sub>CM</sub>	12		
Continuous Collector Current	(Note 3)		4.5		
Continuous Collector Current	(Note 4)	IC	5	A	
Base Current		I <sub>B</sub>	1		

# Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

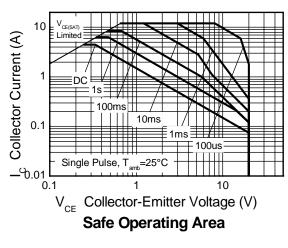
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)		1.5 12	W mW/°C	
Linear Derating Factor	(Note 4)	P <sub>D</sub>	2.45 19.6		
Thermal Desistance Junction to Ambient	(Note 3)	5	83		
Thermal Resistance, Junction to Ambient	(Note 4)	R <sub>θ</sub> JA	51	°C/W	
Thermal Resistance, Junction to Lead	(Note 5)	$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

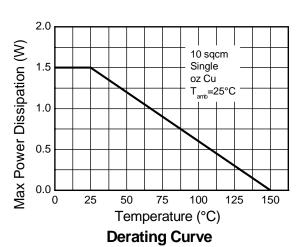
Notes:

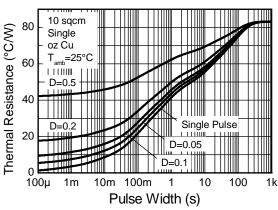
- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 4. Same as note (3), except the device is measured at t ≤ 5 sec.
- 5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

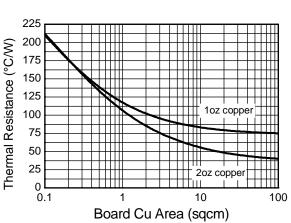


### **Thermal Characteristics**



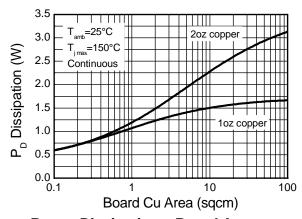






## **Transient Thermal Impedance**

Thermal Resistance v Board Area



**Power Dissipation v Board Area** 



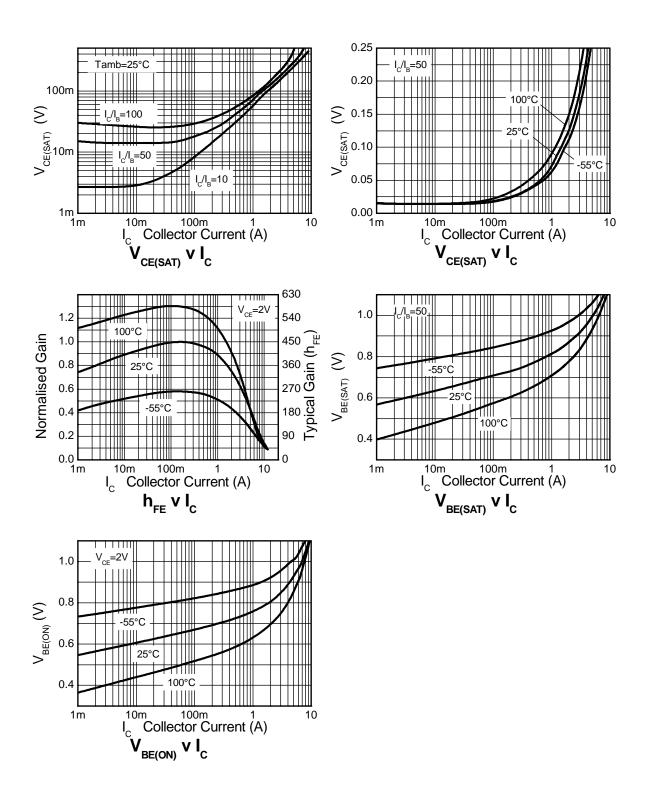
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	40	100	-	V	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV <sub>CEO</sub>	20	27	-	V	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	8.2	-	V	I <sub>E</sub> = 100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 30V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	. nA	V <sub>EB</sub> = 6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 16V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200 300 200 100	400 450 360 180	- - -	-	$I_C = 10 \text{mA}, V_{CE} = 2 \text{V}$ $I_C = 200 \text{mA}, V_{CE} = 2 \text{V}$ $I_C = 2 \text{A}, V_{CE} = 2 \text{V}$ $I_C = 6 \text{A}, V_{CE} = 2 \text{V}$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	- - - -	8 90 115 190 210	15 150 135 250 300	mV	$I_C = 0.1A$ , $I_B = 10mA$ $I_C = 1A$ , $I_B = 10mA$ $I_C = 2A$ , $I_B = 50mA$ $I_C = 3A$ , $I_B = 100mA$ $I_C = 4.5A$ , $I_B = 125mA$
Base-Emitter Turn-On Voltage (Note 6)	V <sub>BE(on)</sub>	-	0.88	0.97	V	$I_C = 4.5A, V_{CE} = 2V$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	0.98	1.07	V	$I_C = 4.5A$ , $I_B = 125mA$
Output Capacitance	$C_{obo}$	-	23	30	pF	$V_{CB} = 10V. f = 1MHz$
Transition Frequency	f <sub>T</sub>	100	140	-	MHz	$V_{CE} = 10V, I_{C} = 50mA,$ f = 100MHz
Turn-On Time	t <sub>on</sub>	-	170	-	ns	$V_{CC} = 10V, I_C = 3A$
Turn-Off Time	t <sub>off</sub>	-	400	-	ns	$I_{B1} = I_{B2} = 10 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

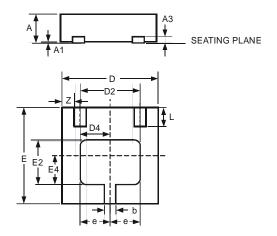


# Typical Electrical Characteristics



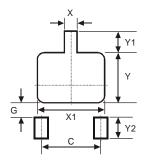


## **Package Outline Dimensions**



DFN2020B-3						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3		_	0.152			
b	0.20	0.30	0.25			
D	1.95	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
е		_	0.65			
Е	1.95	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
L	0.25	0.35	0.30			
Z		_	0.225			
All Dimensions in mm						

# **Suggested Pad Layout**



Dimensions	Value (in mm)		
С	1.30		
G	0.24		
Х	0.35		
X1	1.52		
Y	1.09		
Y1	0.47		
V2	0.50		





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